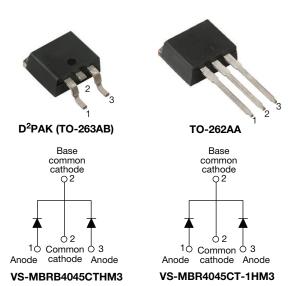
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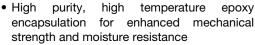
High Performance Schottky Rectifier, 2 x 20 A



| PRIMARY CHARACTERISTICS | | | | | | |
|----------------------------------|---|--|--|--|--|--|
| I _{F(AV)} 2 x 20 A | | | | | | |
| V_{R} | 45 V | | | | | |
| V _F at I _F | 0.58 V | | | | | |
| I _{RM} max. | 95 mA at 125 °C | | | | | |
| T _J max. | 150 °C | | | | | |
| Package | D ² PAK (TO-263AB), TO-262AA | | | | | |
| Circuit configuration | Common cathode | | | | | |
| E _{AS} | 20 mJ | | | | | |

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | |
|-----------------------------------|--|-------------|-------|--|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | | |
| I _{F(AV)} | Rectangular waveform (per device) | 40 | ^ | | | | | |
| I _{FRM} | T _C = 117 °C (per leg) | 40 | Α | | | | | |
| V_{RRM} | | 45 | V | | | | | |
| I _{FSM} | t _p = 5 μs sine | 900 | Α | | | | | |
| V _F | 20 A _{pk} , T _J = 125 °C | 0.58 | V | | | | | |
| TJ | Range | -65 to +150 | °C | | | | | |

| VOLTAGE RATINGS | | | | | | | |
|--------------------------------------|-----------|-------------------------------------|-------|--|--|--|--|
| PARAMETER | SYMBOL | VS-MBRB4045CTHM3, VS-MBR4045CT-1HM3 | UNITS | | | | |
| Maximum DC reverse voltage | V_R | 45 | V | | | | |
| Maximum working peak reverse voltage | V_{RWM} | 45 | V | | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | |
|---|--------------------|---|---|--------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDI | ITIONS | VALUES | UNITS | | | |
| Maximum average per leg | l= | T_C = 118 °C, rated V_B | | 20 | | | | |
| forward current per device | I _{F(AV)} | TC = TT8 C, Tated VR | | 40 | | | | |
| Peak repetitive forward current per leg | I _{FRM} | Rated V _R , square wave, 20 kHz | Rated V _R , square wave, 20 kHz, T _C = 117 °C | | | | | |
| Maximum peak one cycle non-repetitive | 1 | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with | 900 | A | | | |
| peak surge current per leg | IFSM | 10 ms sine or 6 ms rect. pulse | rated V _{RRM} applied | 210 | | | | |
| Non-repetitive avalanche energy per leg | E _{AS} | $T_J = 25 ^{\circ}\text{C}, I_{AS} = 3 \text{A}, L = 4.4 \text{mH}$ | | 20 | mJ | | | |
| Repetitive avalanche current per leg | I _{AR} | Current decaying linearly to zer Frequency limited by T _J maxim | 3 | Α | | | | |



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| ELECTRICAL SPECIFICATIONS | | | | | | | | |
|---------------------------------------|--------------------------------|-----------------------------------|-------------------------|--------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST (| CONDITIONS | VALUES | UNITS | | | |
| | | 20 A | T 05 °C | 0.60 | | | | |
| Maximum forward valtage dres | V (1) | 40 A | T _J = 25 °C | 0.80 | V | | | |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 20 A | T 105 %C | 0.58 | | | | |
| | | 40 A | T _J = 125 °C | 0.80 | | | | |
| | | T _J = 25 °C | | 1 | mA | | | |
| Maximum instantaneous reverse current | I _{RM} ⁽¹⁾ | T _J = 100 °C | Rated DC voltage | 50 | | | | |
| reverse current | | T _J = 125 °C | | 95 | | | | |
| Maximum junction capacitance | C _T | $V_R = 5 V_{DC}$ (test signal I | 900 | pF | | | | |
| Typical series inductance | L _S | Measured from top of | 8.0 | nH | | | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | Rated V _B | | | | | |

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|--|-------------------|--|-------------|------------------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Maximum junction temperature range | T_J | | -65 to +150 | °C | | | |
| Maximum storage temperature range | T _{Stg} | | -65 to +175 | O | | | |
| Maximum thermal resistance, junction to case per leg | R _{thJC} | DC operation | 1.5 | | | | |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth and greased (only for TO-220) | 0.50 | °C/W | | | |
| Maximum thermal resistance, junction to ambient | R _{thJA} | DC operation (for D ² PAK (TO-263AB) and TO-262AA) | 50 | | | | |
| Approximate weight | | | 2 | g | | | |
| Approximate weight | | | 0.07 | OZ. | | | |
| Mounting torque minimum | | Non-lubricated threads | 6 (5) | kgf · cm | | | |
| Mounting torque maximum | | Non-jubricated tifreads | 12 (10) | (lbf \cdot in) | | | |
| Marking daying | | Case style D ² PAK (TO-263AB) | MBRB4 | 045CTH | | | |
| Marking device | | Case style TO-262AA | MBR404 | 5CT-1H | | | |

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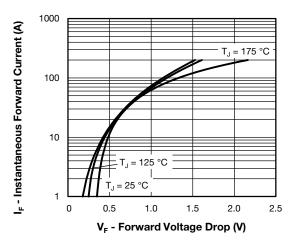


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

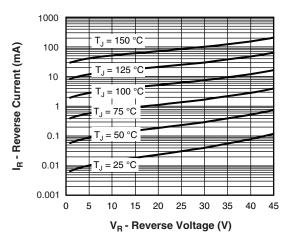


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

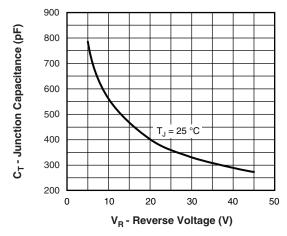


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

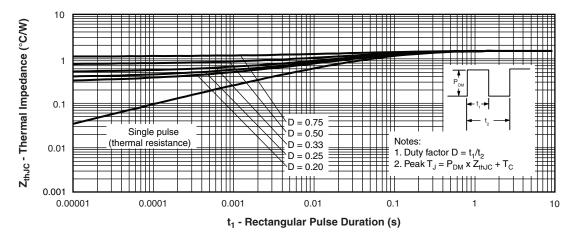


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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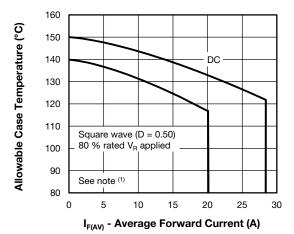


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

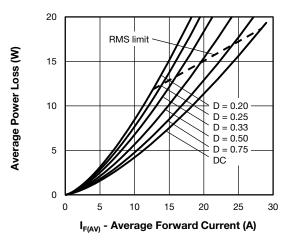


Fig. 6 - Forward Power Loss Characteristics

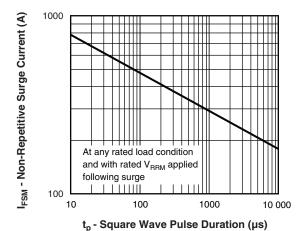


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

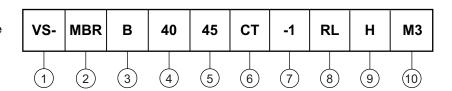
Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; \ I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Essential part number

3 - • B = D^2PAK 7 None

• None = TO-262 **7** = -1

4 - Current rating (40 = 40 A)

- Voltage rating (45 = 45 V)

CT = Essential part number

- • None = D^2PAK 3 = B

• -1 = TO-262 **3** None

8 - • None = Tube

• L = Tape and reel (left oriented - for D²PAK only)

• R = Tape and reel (right oriented - for D²PAK only)

9 - H = AEC-Q101 qualified

10 - Environmental digit:

M3 = Halogen-free, RoHS-compliant and termination lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | | | |
|---|-----|------|-------------------------|--|--|--|--|--|
| PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION | | | | | | | | |
| VS-MBRB4045CTHM3 | 50 | 1000 | Antistatic plastic tube | | | | | |
| VS-MBR4045CT-1HM3 | 50 | 1000 | Antistatic plastic tube | | | | | |
| VS-MBRB4045CTLHM3 | 800 | 800 | 13" diameter reel | | | | | |
| VS-MBRB4045CTRHM3 | 800 | 800 | 13" diameter reel | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|-------------------------------|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?95046 | | | | | |
| Differsions | TO-262AA | www.vishay.com/doc?95419 | | | | |
| Part marking information | D ² PAK (TO-263AB) | www.vishay.com/doc?95444 | | | | |
| Part marking information | TO-262AA | www.vishay.com/doc?95443 | | | | |
| Packaging information | D ² PAK (TO-263AB) | www.vishay.com/doc?95032 | | | | |



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIMETERS | | INCHES | | NOTES | SYMBOL | MILLIM | ETERS | INC | HES | NOTES | |
|----------|-------------|-------|--------|-------|-------|--------|---------|-------|-------|-------|-------|-------|
| STIVIBUL | MIN. | MAX. | MIN. | MAX. | NOIES | NOIES | STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | | Е | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | | е | 2.54 | BSC | 0.100 |) BSC | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | | L3 | 0.25 | BSC | 0.010 | BSC | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIM | IETERS | INC | HES | NOTES |
|---------|----------|--------|-------|-------|-------|
| STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | |
| A1 | 2.03 | 3.02 | 0.080 | 0.119 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.38 | 0.74 | 0.015 | 0.029 | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 BSC | | 0.10 | D BSC | |
| L | 13.46 | 14.10 | 0.530 | 0.555 | |
| L1 | - | 1.65 | - | 0.065 | 3 |
| L2 | 3.36 | 3.71 | 0.132 | 0.146 | |

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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